CMOS Digital Integrated Circuits Silicon Monolithic

TC7SZ08F

1. Functional Description

- 2-Input AND Gate

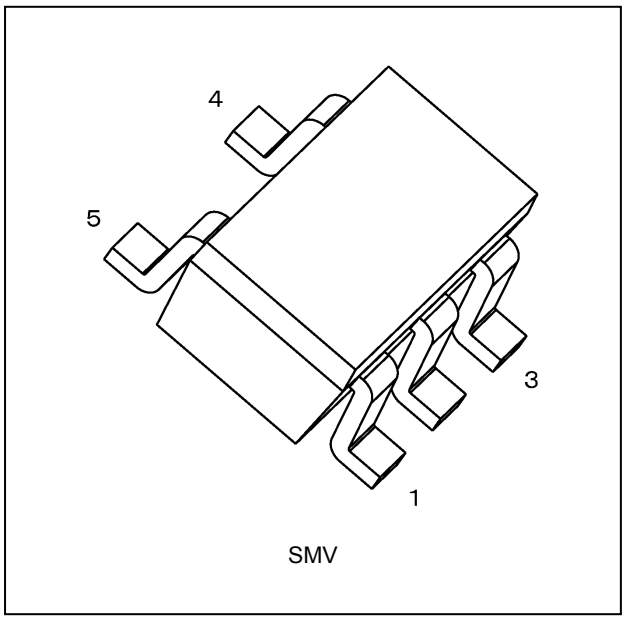
2. Features

(1) AEC-Q100 (Rev. H) (Note 1)
(2) Wide operating temperature range: T_{opr} = -40 to 125 °C (Note 2)
(3) High output current: ±24 mA (min) at V_{CC} = 3.0 V
(4) Super high speed operation: t_{pd} = 2.7 ns (typ.) at V_{CC} = 5.0 V, C_L = 50 pF
(5) Operation voltage range: V_{CC} = 1.65 to 5.5 V
(6) 5.5 V tolerant inputs
(7) 5.5 V power down protection output
(8) Matches the performance of TC74LCX series when operated at 3.3 V V_{CC}

Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

Note 2: For devices with the ordering part number ending in J(CT. T_{opr} = -40 to 85 °C for the other devices.

3. Packaging

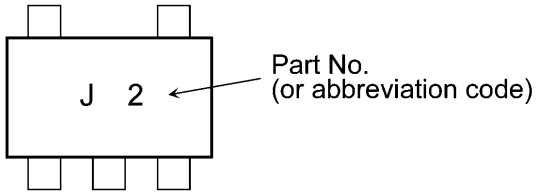


SMV

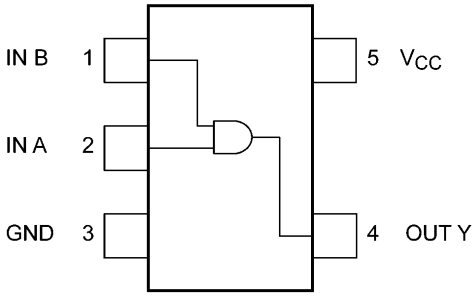
Start of commercial production
1998-08

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4. Marking and Pin Assignment



Marking



Pin Assignment (Top view)

5. IEC Logic Symbol



6. Truth Table

A	B	Y
L	L	L
L	H	L
H	L	L
H	H	H

7. Absolute Maximum Ratings (Note) (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V_{CC}		-0.5 to 6.0	V
Input voltage	V_{IN}		-0.5 to 6.0	V
DC output voltage	V_{OUT}	(Note 1)	-0.5 to 6.0	V
		(Note 2)	-0.5 to V_{CC} + 0.5	
Input diode current	I_{IK}		-20	mA
Output diode current	I_{OK}	(Note 3)	-20	mA
DC output current	I_{OUT}		±50	mA
V_{CC}/ground current	I_{CC}		±50	mA
Power dissipation	P_D		200	mW
Storage temperature	T_{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: V_{CC} = 0 V
Note 2: High (H) or Low (L) state. I_{OUT} absolute maximum rating must be observed.
Note 3: V_{OUT} < GND

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8. Operating Ranges (Note)

Characteristics	Symbol	Note	Test Condition	Rating	Unit
Supply voltage	V_{CC}		—	1.65 to 5.5	V
		(Note 1)	—	1.5 to 5.5	
Input voltage	V_{IN}		—	0 to 5.5	V
Output voltage	V_{OUT}	(Note 2)	—	0 to 5.5	V
		(Note 3)	—	0 to V_{CC}	
Operating temperature	T_{opr}	(Note 4)	—	-40 to 125	°C
		(Note 5)	—	-40 to 85	
Input rise and fall time	dt/dv		V_{CC} = 1.8 ± 0.15 V , 2.5 ± 0.2 V	0 to 20	ns/V
			V_{CC} = 3.3 ± 0.3 V	0 to 10	
			V_{CC} = 5.0 ± 0.5 V	0 to 5	

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either V_{CC} or GND.

Note 1: Data retention only

Note 2: V_{CC} = 0 V

Note 3: High (H) or Low (L) state.

Note 4: For devices with the ordering part number ending in J(CT.

Note 5: For devices except those with the ordering part number ending in J(CT.

9. Electrical Characteristics

9.1. DC Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Test Condition		V_{CC} (V)	Min	Typ.	Max	Unit
High-level input voltage	V_{IH}	—		1.65 to 1.95	V_{CC} × 0.88	—	—	V
				2.3 to 5.5	V_{CC} × 0.75	—	—	
Low-level input voltage	V_{IL}	—		1.65 to 1.95	—	—	V_{CC} × 0.12	V
				2.3 to 5.5	—	—	V_{CC} × 0.25	
High-level output voltage	V_{OH}	V_{IN} = V_{IH}	I_{OH} = -100 μA	1.65	1.55	1.65	—	V
				2.3	2.2	2.3	—	
				3.0	2.9	3.0	—	
				4.5	4.4	4.5	—	
			I_{OH} = -8 mA	2.3	1.9	2.15	—	
			I_{OH} = -16 mA	3.0	2.4	2.8	—	
			I_{OH} = -24 mA	3.0	2.3	2.68	—	
			I_{OH} = -32 mA	4.5	3.8	4.2	—	
Low-level output voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 100 μA	1.65	—	0.0	0.1	V
				2.3	—	0.0	0.1	
				3.0	—	0.0	0.1	
				4.5	—	0.0	0.1	
			I_{OL} = 8 mA	2.3	—	0.1	0.3	
			I_{OL} = 16 mA	3.0	—	0.15	0.4	
			I_{OL} = 24 mA	3.0	—	0.22	0.55	
			I_{OL} = 32 mA	4.5	—	0.22	0.55	
Input leakage current	I_{IN}	V_{IN} = 5.5 V or GND		0 to 5.5	—	—	±1.0	μA
Power-OFF leakage current	I_{OFF}	V_{IN} or V_{OUT} = 5.5 V		0	—	—	1	μA
Quiescent supply current	I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	—	2	μA

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9.2. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Test Condition		V_{CC} (V)	Min	Max	Unit
High-level input voltage	V_{IH}	—		1.65 to 1.95	V_{CC} × 0.88	—	V
				2.3 to 5.5	V_{CC} × 0.75	—	
Low-level input voltage	V_{IL}	—		1.65 to 1.95	—	V_{CC} × 0.12	V
				2.3 to 5.5	—	V_{CC} × 0.25	
High-level output voltage	V_{OH}	V_{IN} = V_{IH}	I_{OH} = -100 μA	1.65	1.55	—	V
				2.3	2.2	—	
				3.0	2.9	—	
				4.5	4.4	—	
			I_{OH} = -8 mA	2.3	1.9	—	
			I_{OH} = -16 mA	3.0	2.4	—	
			I_{OH} = -24 mA	3.0	2.3	—	
			I_{OH} = -32 mA	4.5	3.8	—	
Low-level output voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 100 μA	1.65	—	0.1	V
				2.3	—	0.1	
				3.0	—	0.1	
				4.5	—	0.1	
			I_{OL} = 8 mA	2.3	—	0.3	
			I_{OL} = 16 mA	3.0	—	0.4	
			I_{OL} = 24 mA	3.0	—	0.55	
			I_{OL} = 32 mA	4.5	—	0.55	
Input leakage current	I_{IN}	V_{IN} = 5.5 V or GND		0 to 5.5	—	±10.0	μA
Power-OFF leakage current	I_{OFF}	V_{IN} or V_{OUT} = 5.5 V		0	—	10	μA
Quiescent supply current	I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	20	μA

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9.3. DC Characteristics (Note) (Unless otherwise specified, T_a = -40 to 125 °C)

Characteristics	Symbol	Test Condition		V_{CC} (V)	Min	Max	Unit
High-level input voltage	V_{IH}	—		1.65 to 1.95	V_{CC} × 0.88	—	V
				2.3 to 5.5	V_{CC} × 0.75	—	
Low-level input voltage	V_{IL}	—		1.65 to 1.95	—	V_{CC} × 0.12	V
				2.3 to 5.5	—	V_{CC} × 0.25	
High-level output voltage	V_{OH}	V_{IN} = V_{IH}	I_{OH} = -100 μA	1.65	1.55	—	V
				2.3	2.2	—	
				3.0	2.9	—	
				4.5	4.4	—	
			I_{OH} = -8 mA	2.3	1.7	—	
			I_{OH} = -16 mA	3.0	2.2	—	
			I_{OH} = -24 mA	3.0	2.0	—	
			I_{OH} = -32 mA	4.5	3.4	—	
Low-level output voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 100 μA	1.65	—	0.1	V
				2.3	—	0.1	
				3.0	—	0.1	
				4.5	—	0.1	
			I_{OL} = 8 mA	2.3	—	0.45	
			I_{OL} = 16 mA	3.0	—	0.6	
			I_{OL} = 24 mA	3.0	—	0.8	
			I_{OL} = 32 mA	4.5	—	0.8	
Input leakage current	I_{IN}	V_{IN} = 5.5 V or GND		0 to 5.5	—	±20.0	μA
Power-OFF leakage current	I_{OFF}	V_{IN} or V_{OUT} = 5.5 V		0	—	100	μA
Quiescent supply current	I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	200	μA

Note: For devices with the ordering part number ending in J(CT.

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9.4. AC Characteristics (Unless otherwise specified, T_a = 25 °C, Input: $t_r = t_f$ = 3 ns)

Characteristics	Symbol	Note	Test Condition	V_{CC} (V)	C_L (pF)	Min	Typ.	Max	Unit
Propagation delay time	t_{PLH},t_{PHL}		R_L = 1 MΩ	1.8 ± 0.15	15	2.0	5.2	10.0	ns
				2.5 ± 0.2		0.8	3.4	7.0	
				3.3 ± 0.3		0.5	2.6	4.7	
				5.0 ± 0.5		0.5	2.2	4.1	
			R_L = 500 Ω	3.3 ± 0.3	50	1.5	3.3	5.2	ns
				5.0 ± 0.5		0.8	2.7	4.5	
Input capacitance	C_{IN}		—	0 to 5.5	—	—	4	—	pF
Power dissipation capacitance	C_{PD}	(Note 1)	—	3.3	—	—	20	—	pF
				5.5		—	25	—	

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

9.5. AC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C, Input: $t_r = t_f$ = 3 ns)

Characteristics	Symbol	Test Condition	V_{CC} (V)	C_L (pF)	Min	Max	Unit
Propagation delay time	t_{PLH},t_{PHL}	R_L = 1 MΩ	1.8 ± 0.15	15	2.0	10.5	ns
			2.5 ± 0.2		0.8	7.5	
			3.3 ± 0.3		0.5	5.0	
			5.0 ± 0.5		0.5	4.4	
		R_L = 500 Ω	3.3 ± 0.3	50	1.5	5.5	ns
			5.0 ± 0.5		0.8	4.8	

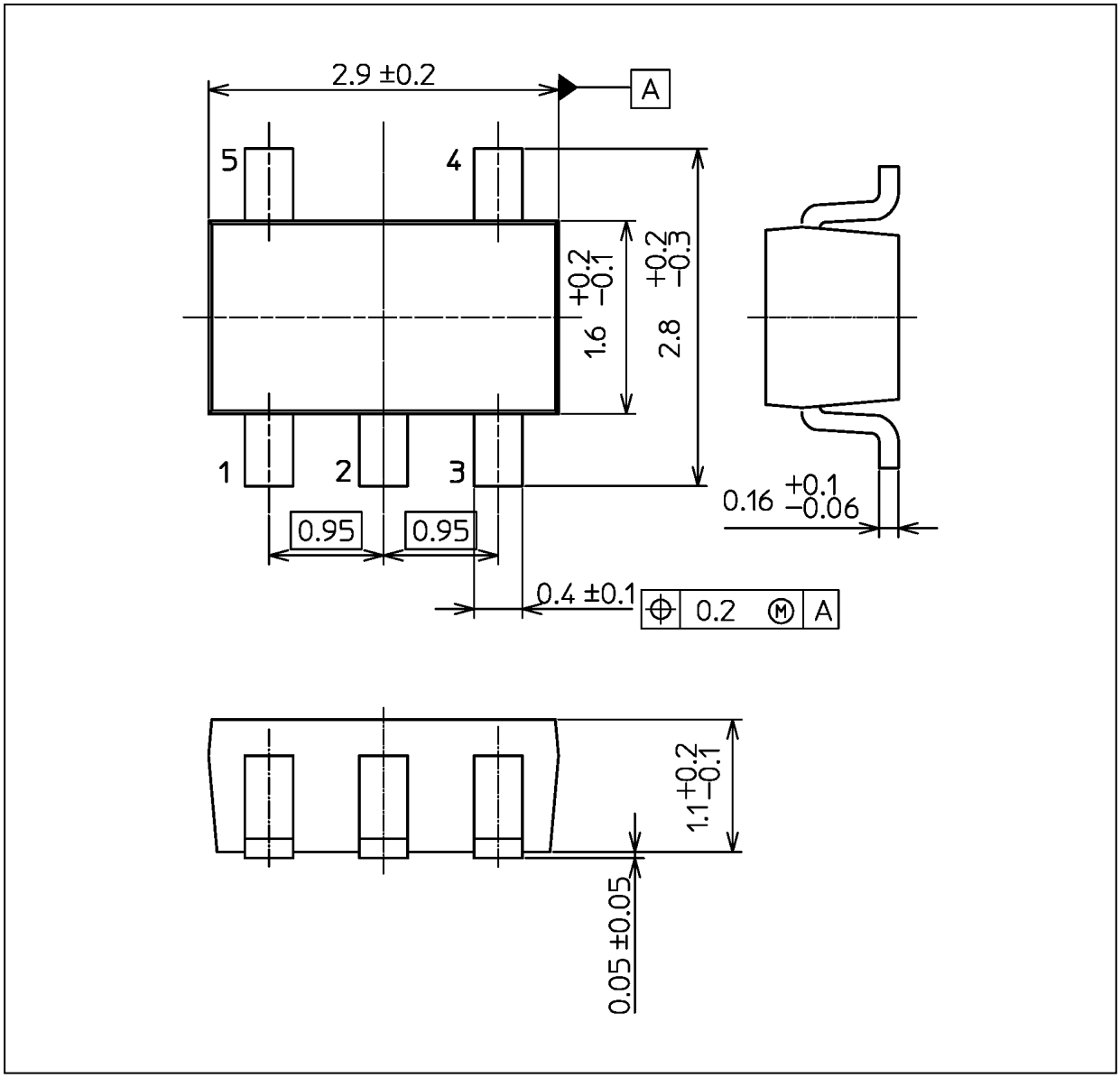
9.6. AC Characteristics (Note) (Unless otherwise specified, T_a = -40 to 125 °C, Input: $t_r = t_f$ = 3 ns)

Characteristics	Symbol	Test Condition	V_{CC} (V)	C_L (pF)	Min	Max	Unit
Propagation delay time	t_{PLH},t_{PHL}	R_L = 1 MΩ	1.8 ± 0.15	15	2.0	12.0	ns
			2.5 ± 0.2		0.8	8.5	
			3.3 ± 0.3		0.5	5.5	
			5.0 ± 0.5		0.5	5.0	
		R_L = 500 Ω	3.3 ± 0.3	50	1.5	6.5	ns
			5.0 ± 0.5		0.8	5.5	

Note: For devices with the ordering part number ending in J(CT.

Package Dimensions

Unit: mm



Weight: 14 mg (typ.)

Package Name(s)
JEDEC: SOT-25
Nickname: SMV

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